TOSHIBA Photocoupler IRED & Photo-Transistor

TLP181

Office Machine
Programmable Controllers
AC Adapter
I/O Interface Board

The TOSHIBA mini flat coupler TLP181 is a small outline coupler, suitable for surface mount assembly.

TLP181 consist of a photo transistor optically coupled to an infrared emitting diode. Since TLP181 is smaller than DIP package, it's suitable for high-density surface mounting applications such as programmable controllers.

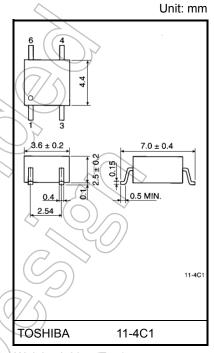
- Collector-emitter voltage: 80 V (min)
- Current transfer ratio: 50% (min)

Rank GB: 100% (min)

- Isolation voltage: 3750 Vrms (min)
- Operation Temperature: -55 to 110 °C
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A

File No.E67349

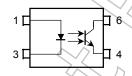
VDE-approved: EN 60747-5-5 (Note 1)



Weight: 0.09 g (Typ.)

Note 1: When a VDE approved type is needed, please designate the **Option(V4)**.

Pin Configuration (top view)



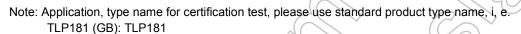
- 1: Anode
- 3: Cathode
- 4: Emitter
- 6: Collector

Start of commercial production 1993-05

Current Transfer Ratio

	Current Trans	sfer Ratio (%) /I _F)	
Classification (Note 1)	I _F = 5mA, V _{CE} :	= 5V, Ta = 25°C	Marking Of Classification
, ,	Min	Max	
Blank	50	600	Blank ,Y■,YE,G,G■,GR,B,BL,GB
Rank Y	50	150	YE, Y■
Rank GR	100	300	GR, G, G [■]
Rank BL	200	600	BL, B
Rank GB	100	600	GB , GR , G, G [■] , BL , B
Rank YH	75	150	Y= ()}
Rank GRL	100	200	G
Rank GRH	150	300	G [®]
Rank BLL	200	400	В

Note 1: EX, Rank GB: TLP181 (GB)



Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	lF	50	mA
	Forward current detating (Ta ≥ 89°C)	ΔI _F /°C	-1.4	mA/°C
	Pulse forward current (100µs pulse, 100pps)	IFP	1	A
LED	Reverse voltage	V _R	5	V
	Diode power dissipation	PD	100	mW
	Diode power dissipation derating (Ta \geq 89°C)	ΔP _D /°C	-2.8	mW/°C
	Junction temperature	Tj	125	(J.C)
	Collector-emitter voltage	V _{CEO}	80	V
	Emitter-collector voltage	V _E CO	7	V
ctor	Collector current	Ic	50	mA
Detector	Collector power dissipation	Pc	150	mW _
	Collector power dissipation derating (Ta ≥ 25°C)	ΔP _C /°C	-1.5	mW/°C
	Junction temperature	Ţ	125) .c
Stor	age temperature range	Tstg	-55 to 125	°C
Оре	rating temperature range	Topr	-55 to 110	CC
Lea	d soldering temperature (10 s)	T _{sol}	260	, e
Total package power dissipation		RT	200	mW
Tota	al package power dissipation derating (Ta ≥ 25°C)	ΔP _T /°C	-2.0	mW/°C
Isola	ation voltage (AC, 60 s, R.H. ≤ 60 %) (Note 1)	BVS	3750	V _{rms}

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two-terminal device: Pin1, 3 shorted together and pins 4, 6 shorted together

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	5	48	V
Forward current	F	_	16	20	mA
Collector current	Ic	ı	1	10	mA

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.



Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R = 5 V	_	_	10	μΑ
	Capacitance	Ст	V = 0 V, f = 1 MHz	/-	30	_	pF
	Collector-emitter breakdown voltage	V _(BR) CEO	I _C = 0.5 mA	80	7	1	V
	Emitter-collector breakdown voltage	V(BR)ECO	I _E = 0.1 mA	7	_	_	V
Detector	Collector dark current	Iceo	V _{CE} = 48 V, (Ambient light below 1000 lx) (Note 1)	<u>)</u> _	0.01 (2)	0.1 (10)	μА
	Collector dark current ICEO	V _{CE} = 48 V, Ta = 85 °C, (Ambient light below 1000 lx) (Note 1)	_	2 (4)	50 (50)	μА	
	Capacitance (collector to emitter)	CCE	V = 0 V, f = 1 MHz	- 0	10	\searrow	pF

Note 1: Please use standard electric lamp to light up the device's marking surface.

Coupled Electrical Characteristics (Ta = 25°C)

	/		$ \langle -\rangle /$ $\langle -\rangle /$ \langle	_			
Characteristic	Symbol	Test Condition		Mln	Тур.	Max	Unit
Current transfer ratio	Je/IF	IF = 5 mA, VCE = 5 V		50	-	600	%
Current transfer fatto	JC/IF		Rank GB	100	1	600	70
Saturated CTR	IC/IF(sat) IF = 1 mA, V _{CE} = 0.4 V	//		60	1	%	
Saturated CTK			Rank GB	30	1	1	70
		IC = 2.4 mA, IF = 8 mA			_	0.4	
Collector-emitter saturation voltage	√ VCE(sat)	I _C = 0.2 mA, I _F = 1 mA		_	0.2		V
			Rank GB	_	_	0.4	
Off-state collector current	IC(off)	V _F = 0.7 V, V _{CE} = 48 V		_	1	10	μА

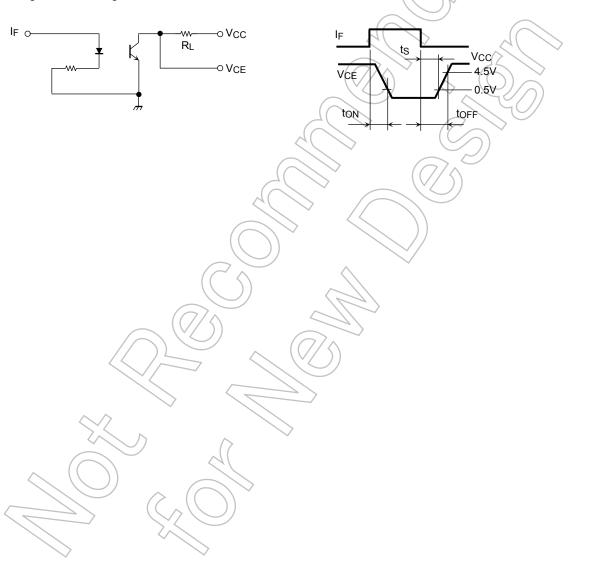
Isolation Characteristics (Ta = 25°C)

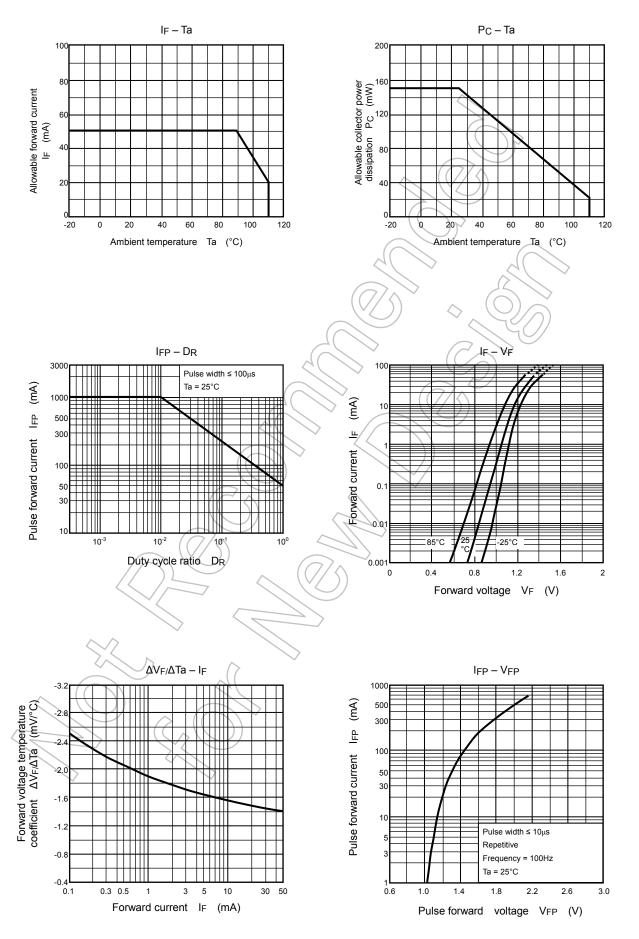
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	Cs	V _S = 0 V, f = 1 MHz	1	8.0	1	pF
Isolation resistance	Rs	V _S = 500 V, R.H. ≤ 60 %	1×10 ¹²	10 ¹⁴	-	Ω
Isolation voltage	BVs	AC, 60 s	3750	_	1	V _{rms}

Switching Characteristics (Ta = 25°C)

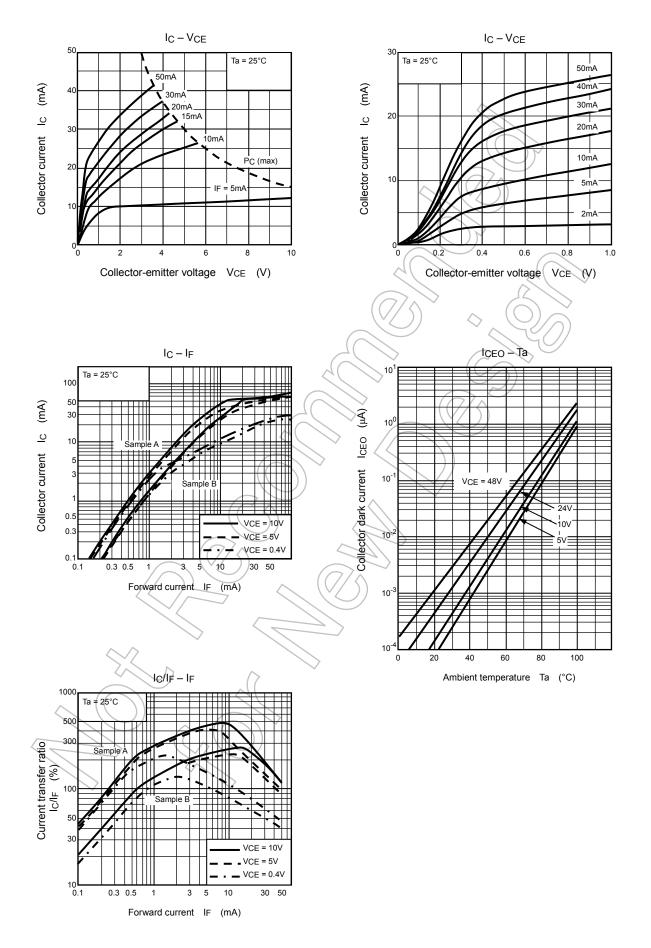
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	t _r		_	2	_	μs
Fall time	t _f	V _{CC} = 10 V, I _C = 2 mA	_	3	_	
Turn-on time	ton	$R_L = 100 \Omega$	/-	3	_	
Turn-off time	t _{off}			3	_	
Turn-on time	ton) 2	_	
Storage time	ts	R_L = 1.9 k Ω (Fig.1) V_{CC} = 5 V, I_F = 16 mA) 	25	_	μS
Turn-off time	toff	VCC = 5 V, IF = 10 IIIA))	40	_	

Fig. 1 Switching time test circuit

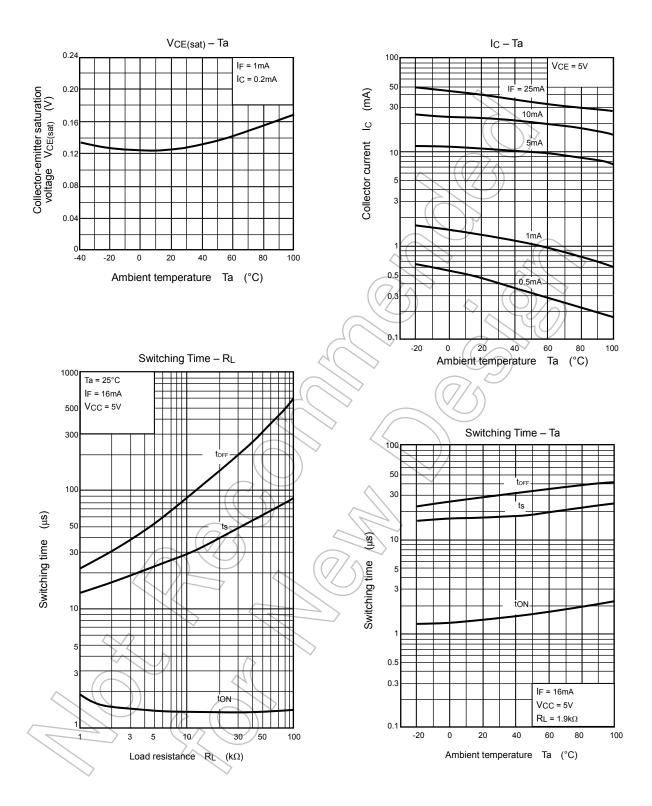




NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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